### **Panasonic**

# **UP04111G**

## Silicon PNP epitaxial planar type

For switching/digital circuits

#### ■ Features

- Two elements incorporated into one package (Transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

#### ■ Basic Part Number

• UNR2111 × 2

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	-50	V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	-50	V
Collector current	$I_{C}$	-100	mA
Total power dissipation	P <sub>T</sub>	125	mW
Junction temperature	$T_{j}$	125	°C
Storage temperature	T <sub>stg</sub>	-55 to +125	°C

#### ■ Package

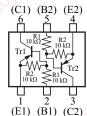
• Code SSMini6-F2

• Pin Name

1: Emitter (Tr1) 4: Emitter (Tr2)
2: Base (Tr1) 5: Base (Tr2)
3: Collector (Tr2) 6: Collector (Tr1)

#### ■ Marking Symbol: 9U

#### ■ Internal Connection

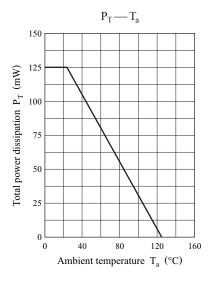


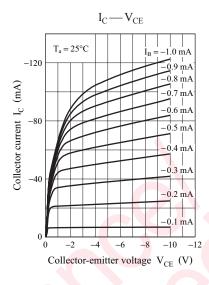
#### ■ Electrical Characteristics $T_a = 25$ °C±3°C

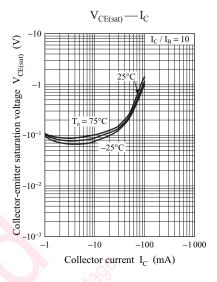
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	$I_{\rm C} = -10 \mu\text{A}, I_{\rm E} = 0$	-50	5	3,	V
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = -2 \text{ mA}, I_{\rm B} = 0$	-50	10.0		V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{\rm CB} = -50 \text{ V}, I_{\rm E} = 0$	30, 20	2//	-0.1	μΑ
Collector-emitter cutoff current (Base open)	I <sub>CEO</sub>	$V_{CE} = -50 \text{ V}, I_{B} = 0$	Silio		-0.5	μΑ
Emitter-base cutoff current (Collector open)	$I_{\mathrm{EBO}}$	$V_{EB} = -6 \text{ V}, I_C = 0$	1,2		-0.5	mA
Forward current transfer ratio	$h_{FE}$	$V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$	35			_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$			-0.25	V
Output voltage high-level	$V_{OH}$	$V_{CC} = -5 \text{ V}, V_{B} = -0.5 \text{ V}, R_{L} = 1 \text{ k}\Omega$	-4.9			V
Output voltage low-level	V <sub>OL</sub>	$V_{CC} = -5 \text{ V}, V_{B} = -2.5 \text{ V}, R_{L} = 1 \text{ k}\Omega$			-0.2	V
Input resistance	$R_1$	016,00 North	-30%	10	+30%	kΩ
Resistance ratio	$R_1/R_2$		0.8	1.0	1.2	_
Transition frequency	$f_T$	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz

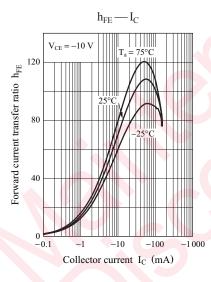
 $Note)\ Measuring\ methods\ are\ based\ on\ JAPANESE\ INDUSTRIAL\ STANDARD\ JIS\ C\ 7030\ measuring\ methods\ for\ transistors.$ 

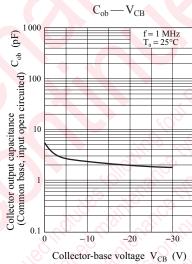
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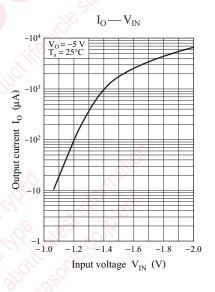


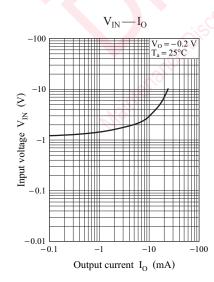








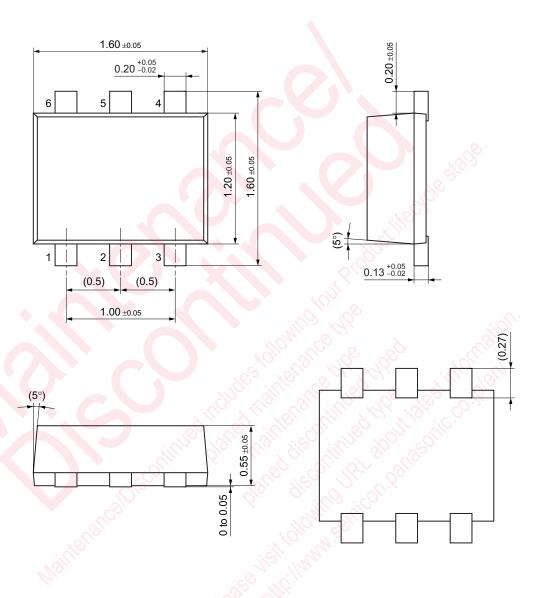




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SSMini6-F2 Unit: mm



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